HIGH ENERGY DIODE PUMPED ALL-SOLID-STATE **Q-SWITCHED LASER**

High energy diode pumped all solid state Q-switched laser at 1064nm has the features of high single pulse energy, short pulse duration, and high peak power, which is widely used in LIBS, LIF, ICP-MS, LCD repair, scientific research, and so on.









SPECIFICATIONS

Wavelength (nm)	1064±1	
Operating mode	Q-switched:EOM(Electro-optic Modulation)	Q-switched: PM(Passive Modulation)
Single pulse energy (mJ)	1~10	
Pulse duration (ns)	<10	
Rep. rate (Hz)	1~10, EXT (adjustable)	
Energy stability (rms)	<2%, <3%, <5%	<5%
Beam divergence, full angle	<3	
Beam diameter (mm)	~3	
Warm-up time (minutes)	<15	
Beam height from base plate (mm)	34	
Cooled method	Air cooled	
Operating temperature (°C)	15~30	
Power supply (220V AC/24V DC)	PSU-DPS-A	
Expected lifetime (pulses)	10 9	
Warranty period	1 year	
Available options	Jitter(Sdev):~1ns (Electro-optic modulation); Battery power supply	





